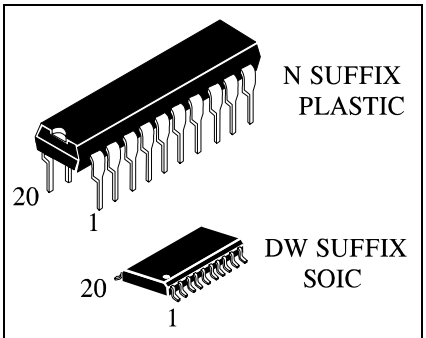
IN74LV374

Octal D-type transparent latch; 3-state

The IN74LV374 is a low-voltage Si-gate CMOS devise and is pin and function compatible with 74HCT374.

The IN74LV374 is an octal D-type transparent latch featuring separate D-type inputs for each latch and 3-state outputs for bus oriented applications. A latch enable (LE) input and an output enable (OE) input are common to all internal latches.

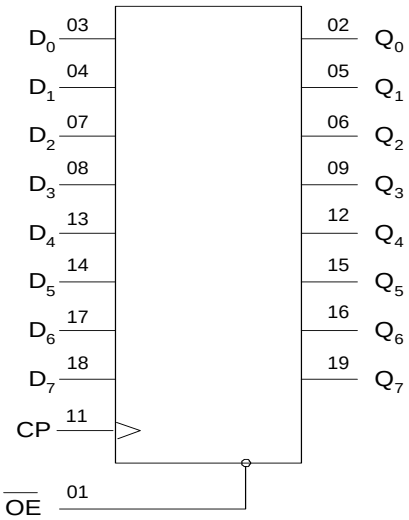
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 1.2 to 3.6 V
- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices



ORDERING INFORMATION

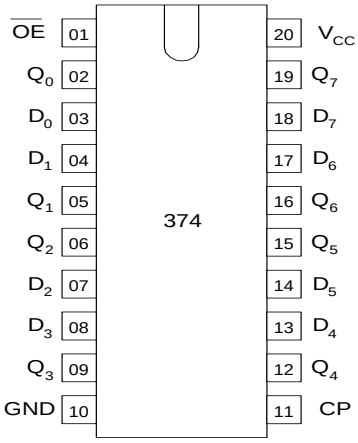
IN74LV374N Plastic
IN74LV374DW SOIC
T_A = -40° to 125° C for all packages

LOGIC DIAGRAM



PIN 20=V_{CC}
PIN 10 = GND

PIN ASSIGNMENT



FUNCTION TABLE

Inputs			Output
$\overline{OE}$	CP	Dn	Qn
L	⌐	H	H
L	⌐	L	L
L	L, H, ⌙	X	Q_0
H	X	X	Z

X = Don't care
Z = High impedance OFF-state
L = Low voltage level
H= HIGH voltage level

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MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage	-0.5 to +5.0	V
I_{IK}*1	DC input diode current	±20	mA
I_{OK}*2	DC output diode current	±50	mA
Io*3	DC output source or sink current -bus driver outputs	±35	mA
I_{GND}	DC V_{CC} or GND current for types with - bus driver outputs	±70	mA
I_{CC}	DC V_{CC} or GND current for types with - bus driver outputs	±70	mA
P_D	Power dissipation per paskade, plastic DIP+ SOIC package+	750 500	mW
Tstg	Storage temperature	-65 to +150	°C
T_L	Lead temperature, 1.5 mm from Case for 10 seconds (Plastic DIP), 0.3 mm (SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 12 mW/°C from 70° to 125°C
SOIC Package: : - 8 mW/°C from 70° to 125°C
*1: $V_I < -0.5$ or $V_I > V_{CC}+0.5V$
*2: $Vo < -0.5$ or $Vo > V_{CC}+0.5V$
*3: $-0.5V < Vo < V_{CC}+0.5V$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		1.2	3.6	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage		0	V_{CC}	V
T_A	Operating Temperature, All Package Types		-40	+125	°C
t_r, t_f	Input Rise and Fall Time	V_{CC} =1.2 V V_{CC} =2.0 V V_{CC} =3.0 V V_{CC} =3.6 V	0 0 0	1000 700 500 400	ns

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \le (V_{IN}$ or $V_{OUT}) \le V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CC}, B	Guaranteed Limit						Unit
				25°C		-40°C to 85°C		-40°C to 125°C		
				min	max	min	max	min	max	
V_{IH}	HIGH level input voltage	$V_O = V_{CC}$-0.1 B	1.2 2.0 3.0 3.6	0.9 1.4 2.1 2.5	- - - -	0.9 1.4 2.1 2.5	- - - -	0.9 1.4 2.1 2.5	- - - -	B
V_{IL}	LOW level input voltage	V_O =0.1 B	1.2 2.0 3.0 3.6	- - - -	0.3 0.6 0.9 1.1	- - - -	0.3 0.6 0.9 1.1	- - - -	0.3 0.6 0.9 1.1	B
V_{OH}	HIGH level output voltage; all outputs	$V_I = V_{IH}$ or V_{IL} I_O = -50 мкА	1.2 2.0 3.0 3.6	1.1 1.92 2.92 3.52	- - - -	1.0 1.9 2.9 3.5	- - - -	1.0 1.9 2.9 3.5	- - - -	B
	HIGH level output voltage; bus driver outputs	$V_I = V_{IH}$ or V_{IL} I_O = -8.0 мА	3.0	2.48	-	2.34	-	2.20	-	B
V_{OL}	LOW-level output voltage; all outputs	$V_I = V_{IH}$ or V_{IL} I_O = 50 мкА	1.2 2.0 3.0 3.6	- - - -	0.09 0.09 0.09 0.09	- - - -	0.1 0.1 0.1 0.1	- - - -	0.1 0.1 0.1 0.1	B
	LOW-level output voltage; bus driver outputs	$V_I = V_{IH}$ or V_{IL} I_O = 8.0 мА	3.0	-	0.33	-	0.4	-	0.5	B
I_{IN}	Input leakage current	$V_I = V_{CC}$ or GND	3.6	-	±0.1	-	±1.0	-	±1.0	мкА
I_{OZ}	3-state output OFF-state current	$V_I = V_{IL}$ or V_{IH} $V_O = V_{CC}$ or GND	1.2 3.6	-	±0.5	-	±5	-	±10	мкА
I_{CC}	Guiescent supply current; MSI	$V_I = V_{CC}$ or 0 B I_O = 0 мкА	3.6	-	8.0	-	80	-	160	мкА

AC ELECTRICAL CHARACTERISTICS (C_L=50 пФ, t_{LH} = t_{HL} = 6.0 нс, V_{IL}=0В, V_{IH}=V_{CC})

Symbol	Parameter	V_{CC} V	Guaranteed Limit						Unit
			25°C		-40°C to 85°C		-40°C to 125°C		
			min	max	min	max	min	max	
t_{PHL},t_{PLH}	Propagation delay CP to Qn	1.2 2.0 3.0	- - -	180 45 27	- - -	230 56 34	- - -	270 68 35	ns
t_{PZH}, t_{PZL}	3-state output enable time OE to Qn	1.2 2.0 3.0	- - -	160 38 25	- - -	200 57 36	- - -	240 68 43	
t_{PHZ}, t_{PLZ}	3-state output disable time OE to Qn	1.2 2.0 3.0	- - -	160 38 23	- - -	200 48 49	- - -	240 58 35	
t_{THL}, t_{TLH}	Output transition time	1.2 2.0 3.0	- - -	75 16 10	- - -	100 20 13	- - -	120 24 15	
t_W	Clock pulse width HING or LOW	1.2 2.0 3.0	250 18 11	- - -	350 23 14	- - -	540 28 17	- - -	
t_{SU}	Set-up time Dn to CP	1.2 2.0 3.0	45 13 8	- - -	50 17 10	- - -	100 20 12	- - -	
t_H	Hold time Dn to CP	1.2 2.0 3.0	25 5 5	- - -	25 5 5	- - -	25 5 5	- - -	
fc	Maxsimum clock pulse freguency	1.2 3.0	27 46		22 37		18 31		
C_I	Input capacitance	3.0	-	7.0	-	7.0	-	7.0	pF

C_{PD}	Power dissipation capacitance per latch	Typical @25°C,V_{CC}=3.0 V	pF
		34	

Used to determine the no-load dynamic power consumption: $P_D=C_{PD}V^2_{CC}fi + \Sigma(C_LV^2_{CC}f_0)$ where:
f_I = input freguency in MHz; C_L= output load capacity in pF;
f_0= output freguency in MHz; V_{CC} = supply voltage in V;
$\Sigma(C_LV^2_{CC}f_0)$ = sum of outputs.

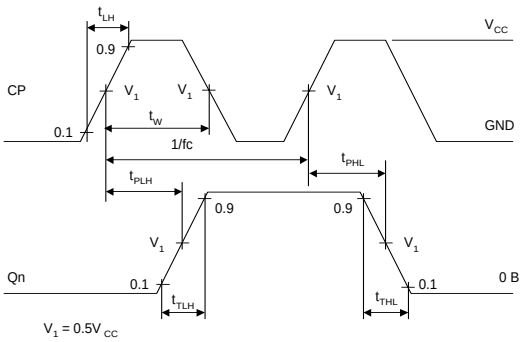


Figure 1. Switching Waveforms

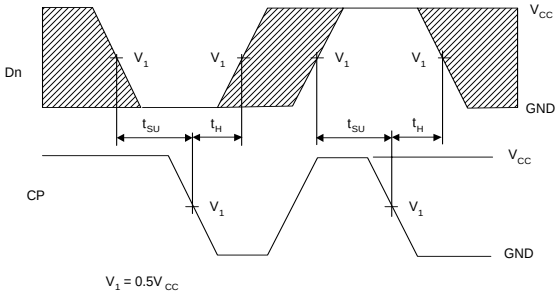


Figure 2. Switching Waveforms

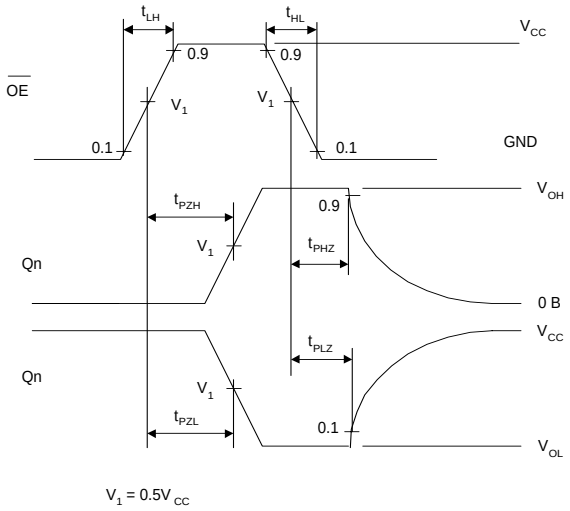
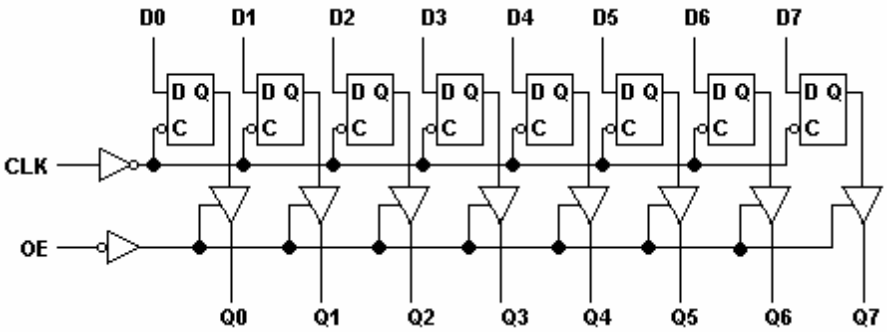
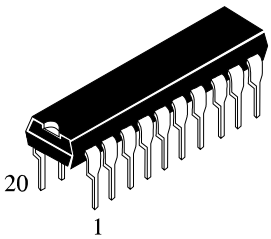


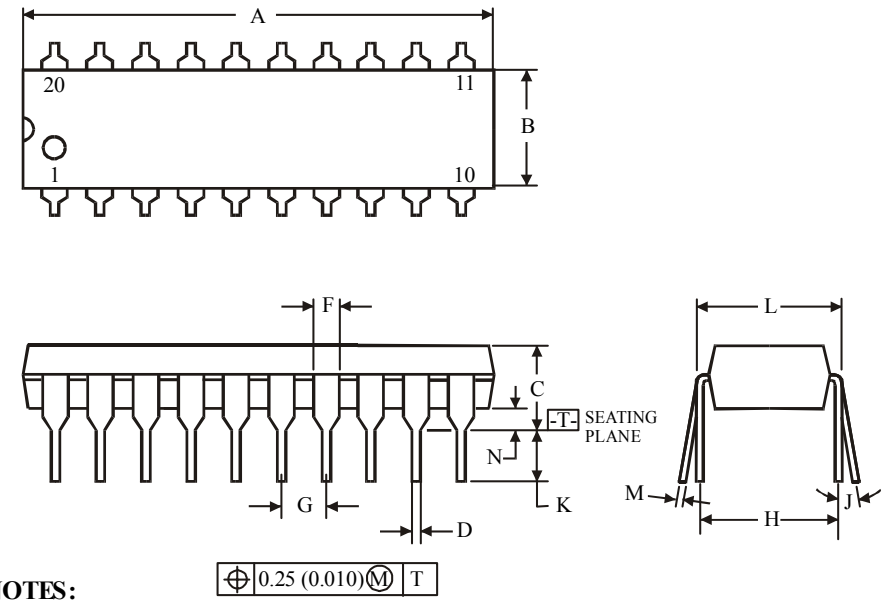
Figure 3. Switching Waveforms

EXPANDED LOGIC DIAGRAM



N SUFFIX PLASTIC DIP
(MS - 001AD)



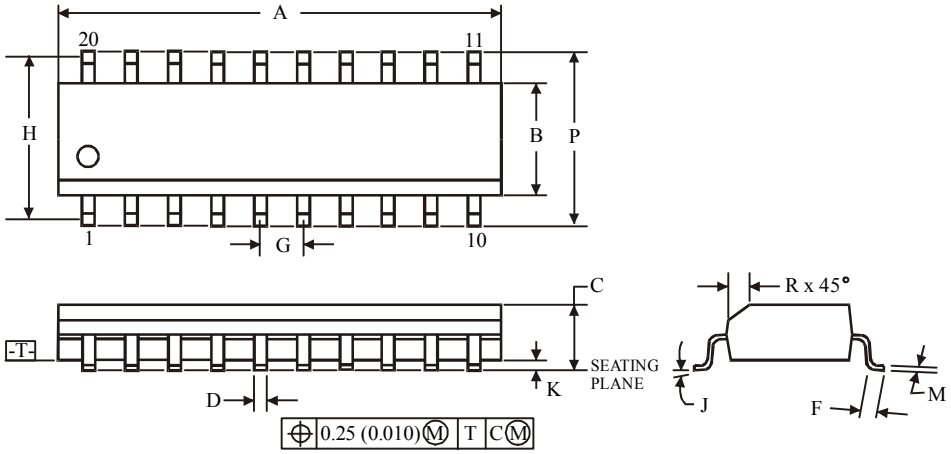


	Dimension, mm	
Symbol	**MIN**	**MAX**
A	24.89	26.92
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

NOTES:

1. Dimensions “A”, “B” do not include mold flash or protrusions.
   Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 013AC)



	Dimension, mm	
Symbol	**MIN**	**MAX**
A	12.6	13
B	7.4	7.6
C	2.35	2.65
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	9.53	
J	0°	8°
K	0.1	0.3
M	0.23	0.32
P	10	10.65
R	0.25	0.75

NOTES:

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side
   for A; for B – 0.25 mm (0.010) per side.